



### **Product Summary**

BV <sub>DSS</sub>	R <sub>DS(ON)</sub> max	l <sub>D</sub> max T <sub>A</sub> = +25°C
60V	2Ω @ V <sub>GS</sub> = 4.5V	380mA
000	2.5Ω @ V <sub>GS</sub> = 2.5V	340mA

### Description

This MOSFET is designed to minimize the on-state resistance (R<sub>DS(ON)</sub>) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

## Applications

- Motor Control
- **Power Management Functions**
- Backlighting

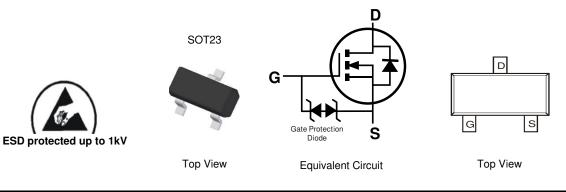
### N-CHANNEL ENHANCEMENT MODE MOSFET

### **Features and Benefits**

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed •
- Low Input/Output Leakage
- ESD Protected Up To 1kV
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

### Mechanical Data

- Case: SOT23
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Annealed over Alloy 42 Leadframe. Solderable per MIL-STD-202, Method 208 @
- Weight: 0.008 grams (Approximate)



## Ordering Information (Note 4)

Part Number	Case	Packaging
DMN62D0U-7	SOT23	3000/Tape & Reel
DMN62D0U-13	SOT23	10000/Tape & Reel

Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com/quality/lead\_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**

3D2	MY

3D2 = Product Type Marking Code YM or  $\overline{Y}M$  = Date Code Marking Y or  $\overline{Y}$  = Year (ex: D = 2016) M = Month (ex: 9 = September)

Data Cada Kay

Date Code K	.ey											
Year	2016	2017	2018	2019	2020	2021	2022	2023	2024	2025	2026	2027
Code	D	E	F	G	Н		J	K	L	М	Ν	0
Month	Jan	Feb	Mar	Apr	Мау	Jun	Jul	Aug	Sep	Oct	Nov	Dec
Code	1	2	3	4	5	6	7	8	9	0	N	D



# **Maximum Ratings** (@ $T_A = +25^{\circ}C$ , unless otherwise specified.)

Characteristic		Symbol	Value	Unit	
Drain-Source Voltage		V <sub>DSS</sub>	60	V	
Gate-Source Voltage		V <sub>GSS</sub>	±20	V	
	Steady State	$T_A = +25^{\circ}C$ $T_A = +70^{\circ}C$	ID	380 300	mA
Continuous Drain Current (Note 6) $V_{GS} = 4.5V$	t<5s	T <sub>A</sub> = +25°C T <sub>A</sub> = +70°C	I <sub>D</sub>	430 340	mA
Maximum Continuous Body Diode Forward Curren	t (Note 6)	Is	0.4	А	
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1%	6) (Note 6	I <sub>DM</sub>	1.2	А	

## Thermal Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)		PD	380	mW
Thermal Deviation to Archivet (Math 5) Steady Stat		5	338	°C/W
Thermal Resistance, Junction to Ambient (Note 5)	t<5s	R <sub>θJA</sub>	292	°C/W
Total Power Dissipation (Note 6)		PD	590	mW
Thermal Resistance, Junction to Ambient (Note 6)		<b>_</b>	216	°C/W
merinal Resistance, Junction to Ambient (Note 6)	t<5s	R <sub>0JA</sub>	177	C/ VV
Operating and Storage Temperature Range		T <sub>J,</sub> T <sub>STG</sub>	-55 to +150	°C

# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

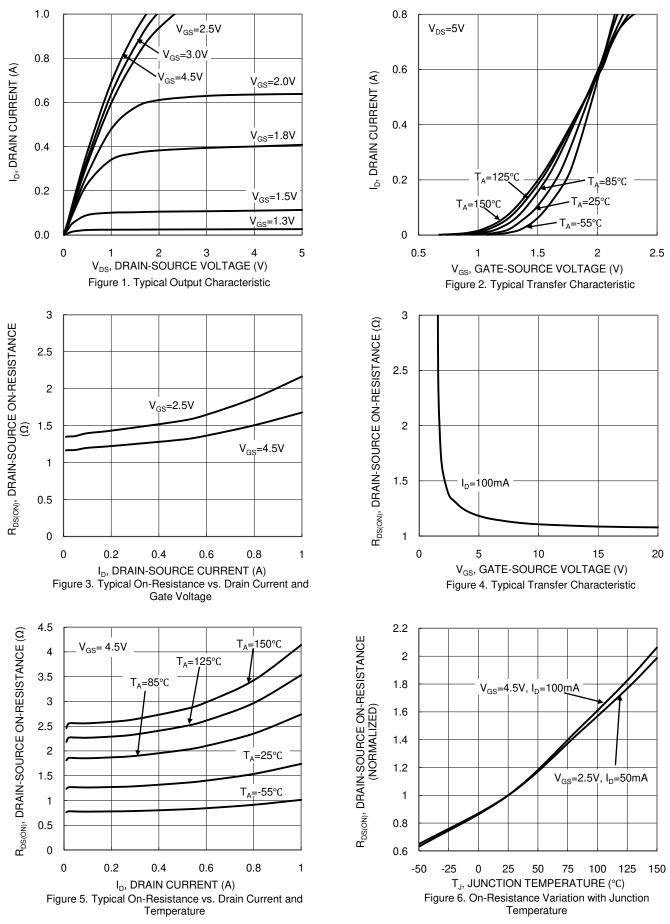
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS (Note 7)	Oymbol	WIIII	тур	WIGA	Onit	rest condition
Drain-Source Breakdown Voltage	BV <sub>DSS</sub>	60	_	_	V	$V_{GS} = 0V, I_{D} = 10\mu A$
Zero Gate Voltage Drain Current	IDSS	_		1.0	μA	$V_{DS} = 60V, V_{GS} = 0V$
Gate-Source Leakage	IGSS	_		±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$
ON CHARACTERISTICS (Note 7)						
Gate Threshold Voltage	V <sub>GS(TH)</sub>	0.5	_	1.0	V	$V_{DS} = 10V, I_D = 250\mu A$
			1.2	2.0		$V_{GS} = 4.5V, I_D = 0.1A$
Static Drain-Source On-Resistance	R <sub>DS(ON)</sub>	—	1.4	2.5	Ω	$V_{GS} = 2.5V, I_D = 0.05A$
			1.8	3.0		$V_{GS} = 1.8V, I_D = 0.05A$
Forward Transconductance	Y <sub>fs</sub>	—	1.8		S	$V_{DS} = 10V, I_D = 0.2A$
Diode Forward Voltage	V <sub>SD</sub>	_	0.8	1.3	V	V <sub>GS</sub> = 0V, I <sub>S</sub> = 115mA
DYNAMIC CHARACTERISTICS (Note 8)						
Input Capacitance	Ciss	_	32	_	pF	
Output Capacitance	Coss	—	3.9		pF	V <sub>DS</sub> = 30V, V <sub>GS</sub> = 0V f = 1.0MHz
Reverse Transfer Capacitance	C <sub>rss</sub>	—	2.4		рF	1 - 1.00012
Gate Resistance	Rg	—	101		Ω	$f = 1MHz$ , $V_{GS} = 0V$ , $V_{DS} = 0V$
Total Gate Charge	Qg	—	0.5		nC	
Gate-Source Charge	Q <sub>gs</sub>	_	0.09	_	nC	V <sub>GS</sub> = 4.5V, V <sub>DS</sub> = 10V, I <sub>D</sub> = 250mA
Gate-Drain Charge	Q <sub>gd</sub>	_	0.09	_	nC	$I_D = 25011A$
Turn-On Delay Time	t <sub>D(ON)</sub>	_	2.4	_	ns	
Turn-On Rise Time	t <sub>R</sub>	_	2.5	_	ns	$V_{DD} = 30V, V_{GS} = 10V,$
Turn-Off Delay Time	tD(OFF)	_	22.6	_	ns	$R_{G} = 25\Omega, I_{D} = 200 \text{mA}$
Turn-Off Fall Time	t <sub>F</sub>	_	12.5		ns	

Notes:

Device mounted on FR-4 PCB, with minimum recommended pad layout.
Device mounted on 1" x 1" FR-4 PCB with high coverage 2oz. Copper, single sided.
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.







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3.5

3

2.5

2

1.5

1

0.5

0

1

-50

-25

0

25

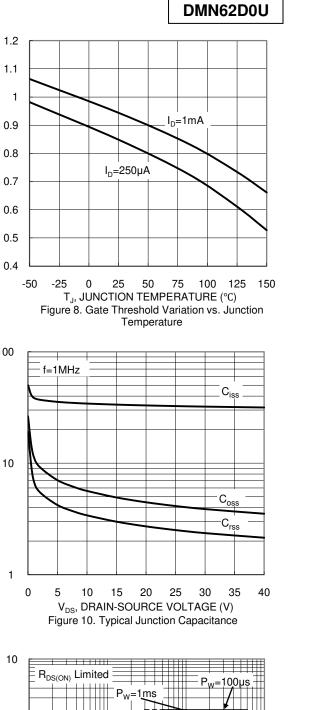
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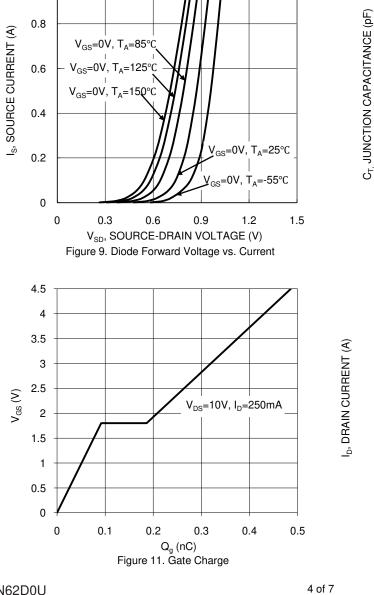
T<sub>.</sub>J, JUNCTION TEMPERATURE (°C)

Figure 7. On-Resistance Variation with Junction Temperature

75

 $R_{\text{DS}(\text{ON})},$  DRAIN-SOURCE ON-RESISTANCE ( $\Omega)$ 



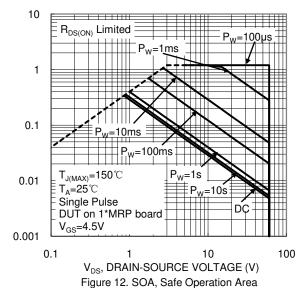


V<sub>GS</sub>=2.5V, I<sub>D</sub>=50mA

V<sub>GS</sub>=4.5V, I<sub>D</sub>=100mA

100 125

150



DMN62D0U Document number: DS38023 Rev. 2 - 2 www.diodes.com

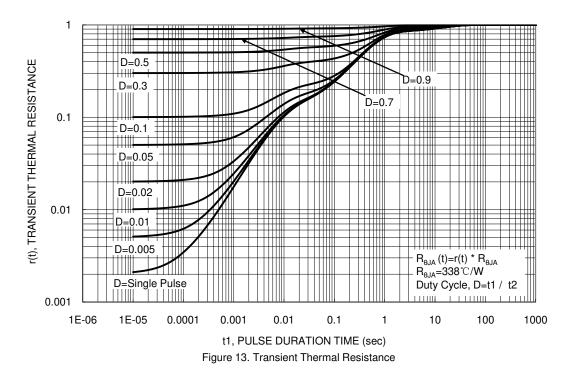
V<sub>GS(TH)</sub>, GATE THRESHOLD VOLTAGE (V)

100

10

1

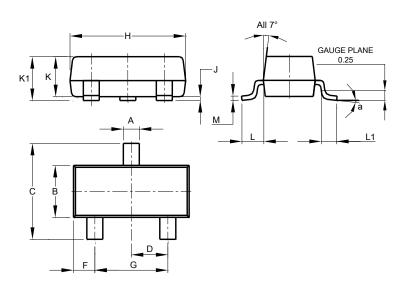






# **Package Outline Dimensions**

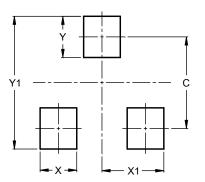
Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT23								
Dim	Min	Тур						
Α	0.37	0.51	0.40					
В	1.20	1.40	1.30					
С	2.30	2.50	2.40					
D	0.89	1.03	0.915					
F	0.45	0.60	0.535					
G	1.78	2.05	1.83					
Н	2.80	3.00	2.90					
J	0.013	0.10	0.05					
К	0.890	1.00	0.975					
K1	0.903	1.10	1.025					
L	0.45	0.61	0.55					
L1	0.25	0.55	0.40					
М	0.085	0.150	0.110					
а	0°	8°						
All	All Dimensions in mm							

# **Suggested Pad Layout**

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
С	2.0
Х	0.8
X1	1.35
Y	0.9
Y1	2.9

SOT23

SOT23



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